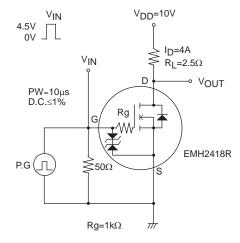
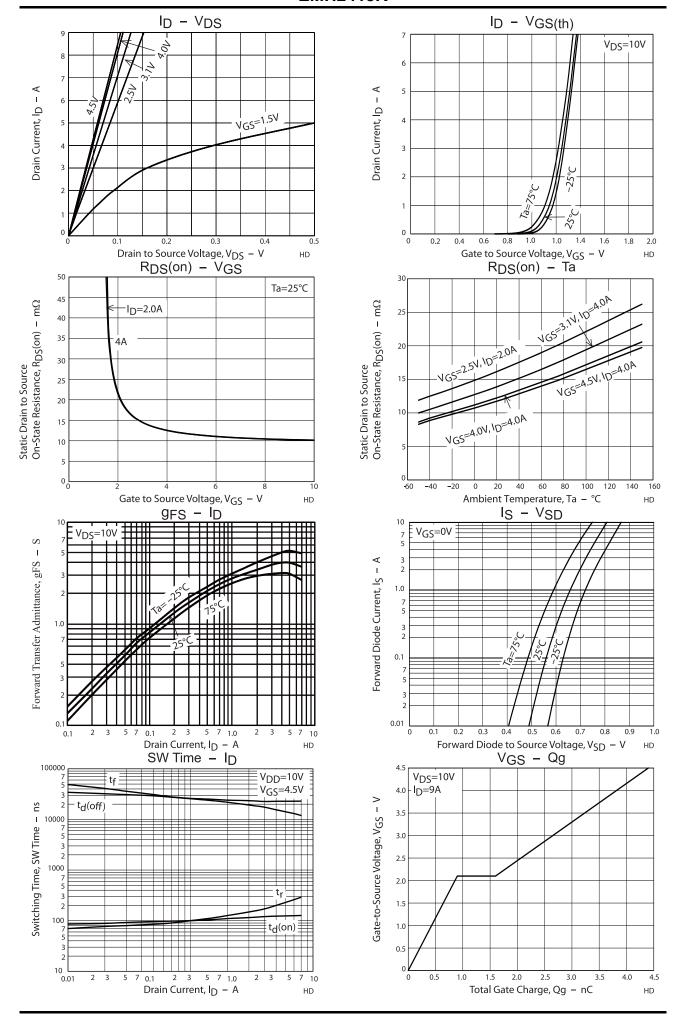
EMH2418R

Electrical Characteristics at Ta = 25°C

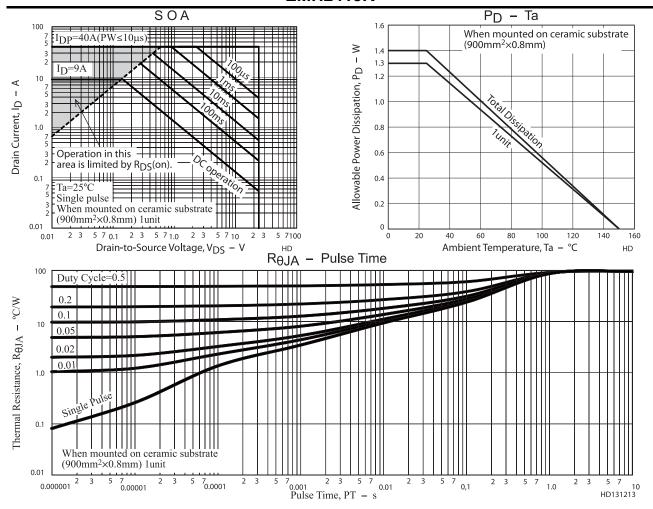
Parameter	Symbol	Conditions	Value			11.3
			min	typ	max	Unit
Drain to Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0V	24			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =20V, V _{GS} =0V			1	μА
Gate to Source Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0V			±1	μΑ
Gate Threshold Voltage	VGS(th)	V _{DS} =10V, I _D =1mA	0.5		1.3	V
Forward Transconductance	9FS	V _{DS} =10V, I _D =4A		4		S
Static Drain to Source On-State Resistance	R _{DS} (on)1	I _D =4A, V _G \$\(\sigma\)=4.5V	9.6	12	15	mΩ
	R _{DS} (on)2	I _D =4A, V _G \$=4.0V	10.0	12.5	16.3	mΩ
	R _{DS} (on)3	I _D =4A, V _G S=3.1V	11.3	14.2	20	mΩ
	R _{DS} (on)4	I _D =2A, V _G S=2.5V	13.2	16.5	23.1	mΩ
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		120		ns
Rise Time	t _r			170		ns
Turn-OFF Delay Time	t _d (off)			17500		ns
Fall Time	tf			22600		ns
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =4.5V, I _D =9A		4.4		nC
Gate to Source Charge	Qgs]		0.9		nC
Gate to Drain "Miller" Charge	Qgd]		0.7		nC
Forward Diode Voltage	V _{SD}	I _S =9A, V _{GS} =0V		0.8	1.2	V

Switching Time Test Circuit





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Package Dimensions

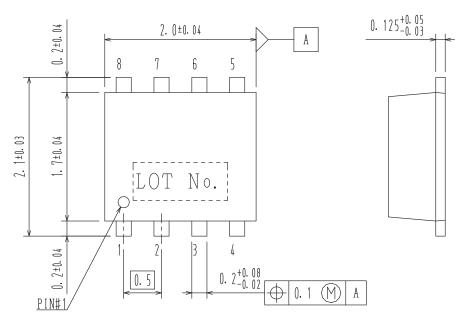
EMH2418R-TL-H

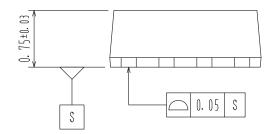
SOT-383FL/EMH8

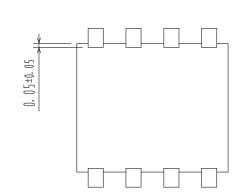
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Unit: mm

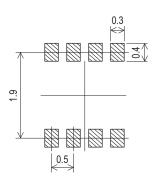
- 1: Source1
- 2: Gate1
- 3: Source2
- 4: Gate2
- 5: Drain
- 6: Drain
- 7: Drain
- 8: Drain







Soldering Footprint



EMH2418R

Note on usage: Since the EMH2418R is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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